APD Semiconductor, Inc.

Super Barrier Rectifier TM

Using state-of-the-art SBR IC process technology, the following features are made possible in a single device:

Major ratings and characteristics

Characteristics	Values	Units
I _{F(AV)} Rectangular Waveform	1.0 *	A
V _{RRM}	20	V
V _F @1A, T _J =75°C	0.34	V, typ
T _J (operating/storage)	-65 to 125	°C

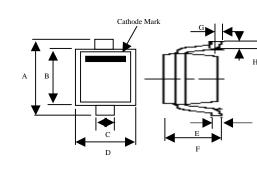
*Note: Device monuted on a glass epoxy board, Board size: 50mm x 50m, Land size: 6mm x 6mm

ELECTRICAL:

- * Low Forward Voltage Drop
- * Low Reverse Leakage
- * Reliable High Temperature Operation
- * Super Barrier Design
- * Softest, fast switching capability
- * 125°C Operating Junction Temperature

MECHANICAL:

* Molded Plastic SOD-323 package



SOD-323				
Di	Min	Max		
А	2.30	2.70		
В	1.60	1.80		
С	0.25	0.40		
D	1.15	1.45		
Е	0.10	0.18		
F	0.85	1.05		
G	-	0.10		
Н	0.20	0.40		
All Dimensions in mm				

	SYMBOL			UNITS
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	V _{RM} V _{RWM} V _{RRM}	20		Volts
Average Rectified Forward Current (Rated V _R -20Khz Square Wave) - 50% duty cycle	I _O ⁽¹⁾	1		Amps
Peak Forward Surge Current - 1/2 60hz	I _{FSM}	18		Amps
Instantaneous Forward Voltage $I_F = 0.7A; T_J = 25^{\circ}C$ $I_F = 1A; T_J = 25^{\circ}C$ $I_F = 0.7A; T_J = 75^{\circ}C$	V _F	Тур 0.38 	Max 0.40 0.34	Volts
Maximum Reverse Current at Rated V_{RM} T _J = 25°C T _J = 75°C	I _R ⁽²⁾	Тур 	Max 0.2 2	mA mA
Operating and Storage Junction Temperature	TJ	-65 to +125		°C

(1) We recommend that the worst case current be no greater than 80% of the maximum rating of I $_{\rm O}$

(2) Pulse width < 300 uS, Duty cycle < 2%

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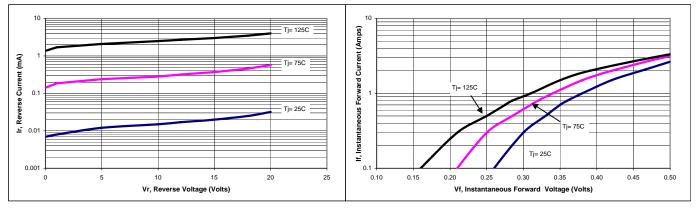


Figure 1: Typical Reverse Current

Figure 2: Typical Forward Voltage

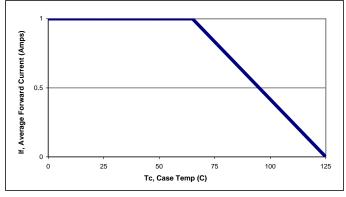
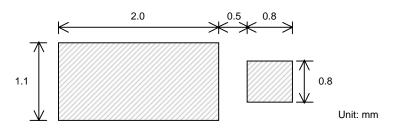


Figure 3: Current Derating, Case*

*Device mounted on a 50mm x 50mm glass epoxy board, 50% duty cycle





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